

**SOT-23 Formed SMD Package**

**BC817  
BC818**

**SILICON PLANAR EPITAXIAL TRANSISTORS**

*N-P-N transistors*

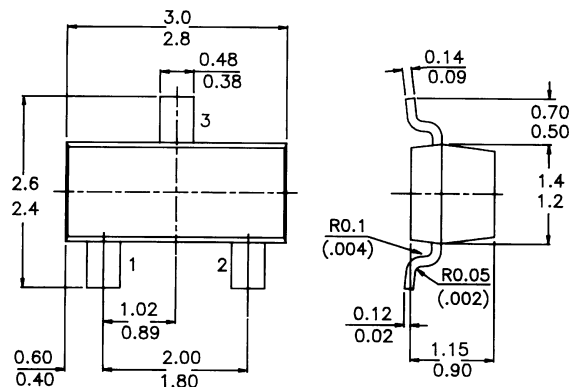
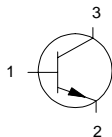
**Marking**

BC817 = 6D  
BC817-16 = 6A  
BC817-25 = 6B  
BC817-40 = 6C  
BC818 = 6H  
BC818-16 = 6E  
BC818-25 = 6F  
BC818-40 = 6G

**PACKAGE OUTLINE DETAILS  
ALL DIMENSIONS IN mm**

**Pin configuration**

1 = BASE  
2 = EMITTER  
3 = COLLECTOR



**ABSOLUTE MAXIMUM RATINGS**

Collector-emitter voltage ( $V_{BE} = 0$ )  
Collector-emitter voltage (open base)  
Collector current (peak value)  
Total power dissipation up to  $T_{amb} = 25^\circ\text{C}$   
Junction temperature  
Transition frequency at  $f = 100\text{ MHz}$   
 $I_C = 10\text{ mA}$ ;  $V_{CE} = 5\text{ V}$

		<b>BC817</b>	<b>BC818</b>	
$V_{CES}$	max.	50	30	V
$V_{CE0}$	max.	45	25	V
$I_{CM}$	max.	1000		mA
$P_{tot}$	max.	250		mW
$T_j$	max.	150		$^\circ\text{C}$
$f_T$	>	100		MHz

# BC817 BC818

**RATINGS** (at  $T_A = 25^\circ\text{C}$  unless otherwise specified)

Limiting values

Collector-emitter voltage ( $V_{BE} = 0$ )

Collector-emitter voltage (open base)

$I_C = 10\text{ mA}$

Emitter-base voltage (open collector)

Collector current (d.c.)

Collector current (peak value)

Emitter current (peak value)

Base current (d.c.)

Base current (peak value)

Total power dissipation up to  $T_{amb} = 25^\circ\text{C}$

Storage temperature

Junction temperature

		<b>BC817</b>	<b>BC818</b>
$V_{CES}$	max.	50	30 V
$V_{CE0}$	max.	45	25 V
$V_{EB0}$	max.	5	5 V
$I_C$	max.	500	mA
$I_{CM}$	max.	1000	mA
$-I_{EM}$	max.	1000	mA
$I_B$	max.	100	mA
$I_{BM}$	max.	200	mA
$P_{tot}$	max.	250	mW
$T_{stg}$		-55 to +150	$^\circ\text{C}$
$T_j$	max.	150	$^\circ\text{C}$

## THERMAL RESISTANCE

From junction to ambient

$$R_{th\ j-a} = 500\text{ KW}$$

## CHARACTERISTICS

$T_j = 25^\circ\text{C}$  unless otherwise specified

Collector cut-off current

$I_E = 0$ ;  $V_{CB} = 20\text{ V}$ ;  $T_j = 25^\circ\text{C}$

$I_E = 0$ ;  $V_{CB} = 20\text{ V}$ ;  $T_j = 150^\circ\text{C}$

Emitter cut-off current

$I_C = 0$ ;  $V_{EB} = 5\text{ V}$

Base emitter voltage \*

$I_C = 500\text{ mA}$ ;  $V_{CE} = 1\text{ V}$

Saturation voltage

$I_C = 500\text{ mA}$ ;  $I_B = 50\text{ mA}$

D.C. current gain

$I_C = 500\text{ mA}$ ;  $V_{CE} = 1\text{ V}$

$I_C = 100\text{ mA}$ ;  $V_{CE} = 1\text{ V}$ ; BC817/BC818

BC817-16

BC818-16

BC817-25

BC818-25

BC817-40

BC818-40

Transition frequency at  $f = 100\text{ MHz}$

$I_C = 10\text{ mA}$ ;  $V_{CE} = 5\text{ V}$

Collector capacitance at  $f = 1\text{ MHz}$

$I_E = I_e = 0$ ;  $V_{CB} = 10\text{ V}$

$I_{CB0}$	<	100 nA
$I_{CB0}$	<	5 $\mu\text{A}$
$I_{EB0}$	<	10 $\mu\text{A}$
$V_{BE}$	<	1,2 V
$V_{CEsat}$	<	700 mV
$h_{FE}$	>	40
$h_{FE}$		100 to 600
$h_{FE}$		100 to 250
$h_{FE}$		160 to 400
$h_{FE}$		250 to 600
$f_T$	>	100 MHz
$C_c$	typ.	5 pF

## Notes

### Disclaimer

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